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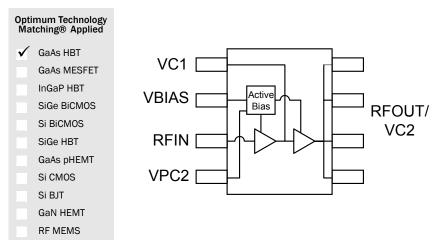
# SPA-2118(Z)

850 MHz 1 WATT POWER AMPLIFIER WITH ACTIVE BIAS

#### RoHS Compliant and Pb-Free Product (Z Part Number) Package: ESOP-8

### **Product Description**

RFMD's SPA-2118 is a high efficiency GaAs Heterojunction Bipolar Transistor (HBT) amplifier housed in a low-cost surface-mountable plastic package. These HBT amplifiers are fabricated using molecular beam epitaxial growth technology which produces reliable and consistent performance from wafer to wafer and lot to lot. This product is specifically designed for use as a driver amplifier for infrastructure equipment in the 850MHz band. Its high linearity makes it an ideal choice for multi-carrier and digital applications.



### Features

- High Linearity Performance
- +20.7 dBm, IS-95 CDMA Channel Power at -55 dBc ACP
- +47 dBm Typ. OIP3
- High Gain: 33dB Typ.
- On-Chip Active Bias Control
- Patented high Reliability GaAs HBT Technology
- Surface-Mountable Plastic Package

### **Applications**

- IS-95 CDMA Systems
- Multi-Carrier Applications
- AMPS, ISM Applications

Devementer	Specification			Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Frequency of Operation	810	900	960	MHz		
Output Power at 1dB Compression		29.0		dBm		
Adjacent Channel Power		-55.0	-52.0	dBc	IS-95 at 880MHz, ±885KHz offset, P <sub>OUT</sub> =20.7dBm	
Small Signal Gain	31.5	33.0	34.5	dB	880MHz	
Input VSWR		1.5:1				
Output Third Order Intercept Point		47.0		dBm	Power out per tone=+14dBm	
Noise Figure		5.0		dB		
Device Current	360	400	425	mA	I <sub>BIAS</sub> =10mA, I <sub>C1</sub> =70mA, I <sub>C2</sub> =320mA	
Device Voltage	4.75	5.0	5.25	V		
Thermal Resistance (Junction - Lead)		31		°C/W	T <sub>L</sub> =85°C	

Test Conditions:  $Z_0=50\Omega$  Temp=25°C  $V_{CC}=5.0V$ 

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EDS-102012 Rev G

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## **SPA-2118(Z)**



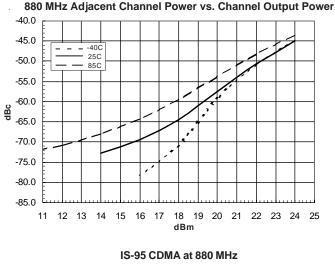
#### **Absolute Maximum Ratings**

5					
Parameter	Rating	Unit			
Max Supply Current ( $I_{C1}$ ) at $V_{CC}$ typ.	150	mA			
Max Supply Current ( $I_{C2}$ ) at $V_{CC}$ typ.	750	mA			
Max Device Voltage (V <sub>CC</sub> ) at I <sub>CC</sub> typ.	6.0	V			
Max RF Input Power	10	dBm			
Max Junction Temp (T <sub>J</sub> )	+160	°C			
Max Storage Temp	+150	°C			
MSL	1				

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

 $I_D V_D < (T_J - T_L) / R_{TH}$ , j-l

850MHz to 950MHz Application Circuit Data, I<sub>CC</sub>=400mA, V<sub>CC</sub>=5V, IS-95, 9 Channels Forward



20 CHPWR 24.02 dBm ACP UP -45.46 dBm 10 ACP LOW 0W -45.07 dBm **T=+25C** ∣ 0 -10 -20 +24 dBm -30 +20 dBm -40 -50 +10-60 16 d -70 Center 880 MHz 600 kHz/ Span 6 MHz



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

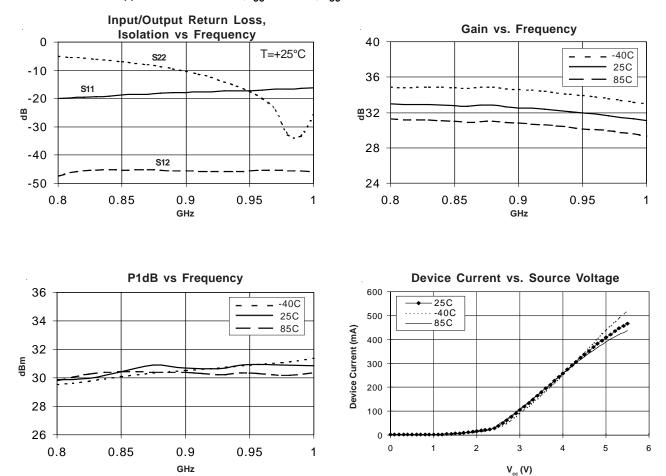
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## SPA-2118(Z)



#### 850MHz to 950MHz Application Circuit Data, $I_{CC}$ =400mA, $V_{CC}$ =5V

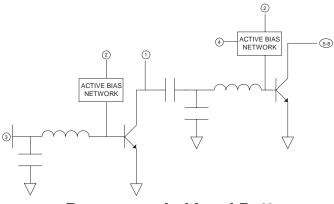


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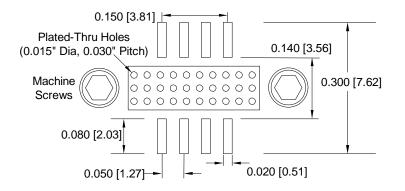
Pin	Function	Description
1	VC1	Supply voltage for the first stage transistor. The configuration as shown on the application schematic is required for opti- mum RF performance.
2	VBIAS	Bias control pin for the active bias network. Recommended configuration is shown in the application schematic.
3	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor as shown in the application shcematic.
4	VPC2	Bias control pin for the active bias network for the second stage. The recommended configuration is shown in the appli- cation schematic.
5, 6, 7, 8	RF OUT/VC2	RF output and bias pin. Bias should be supplied to this pin through an external RF choke. Because DC biasing is present on this pin a DC-blocking capacitor should be used in most applications. (See application schematic.) The supply side of the bias network should be well bypassed. An output matching network is necessary for optimum performance.
EPAD	GND	Exposed area on the bottom side of the package needs to be soldered to the ground plane of the board for thermal and RF performance. Several vias should be located under the EPAD as shown in the recommended land pattern.

## **Simplified Device Schematic**



### **Recommended Land Pattern**

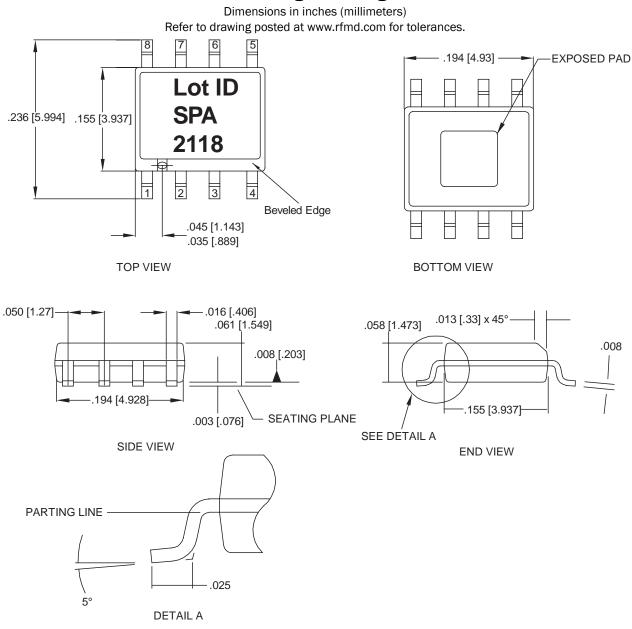
Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.



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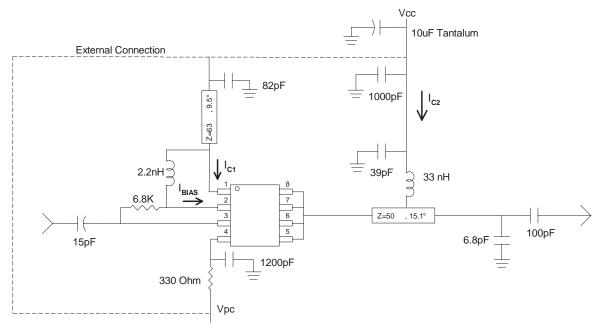






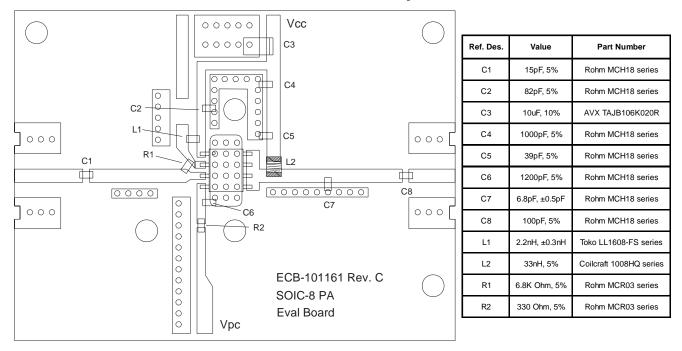
### **Package Drawing**





### 850 MHz to 950 MHz Application Schematic

### 850 MHz to 950 MHz Evaluation Board Layout and Bill of Materials



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### **Part Identification**

The part will be symbolized with an "SPA-2118" for Sn/Pb plating or "SPA-2118Z" for RoHS Compliant Product.

Part Number	Reel Size	Devices/Reel
SPA-2118	7"	500
SPA-2118Z	7"	500

## **Ordering Information**



